

## **Silicon NPN Power Transistor**

#### **DESCRIPTION**

- · Collector-Emitter Breakdown Voltage
  - -V<sub>(BR)CEO</sub>= 50V(Min)
- · Collector-Emitter Saturation Voltage
  - -V<sub>CE(sat)</sub>:0.3V(Max) @I<sub>C</sub>=0.1A

#### **APPLICATIONS**

- · Switching Regulators
- Converters
- · Power Amplifiers



#### ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CEO</sub>	Collector-Emitter Voltage	50	V	
V <sub>CBO</sub>	Collector-Base Voltage	60	V	
V <sub>EBO</sub>	Emitter-Base Voltage	7	V	
lc	Collector Current-Continuous	0.1	А	
I <sub>CP</sub>	Collector Current-Pulse	0.2	А	
Pc	Total Power Dissipation @ Ta=25℃	0.2	W	
TJ	Junction Temperature	150	$^{\circ}$	
T <sub>stg</sub>	Storage Temperature Range	-55~150	$^{\circ}$	



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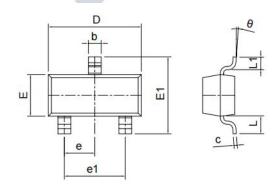
#### **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub>=25°C unless otherwise specified)

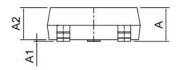
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>СВО</sub>	Collector-base voltage	Ic= 20uA, I <sub>E</sub> = 0	60			V
V <sub>CEO</sub>	Collector-emitter voltage	I <sub>C</sub> = 2mA, I <sub>B</sub> = 0	50			V
V <sub>EBO</sub>	Emitter-base voltage	I <sub>E</sub> = 10uA, I <sub>E</sub> = 0	7			V
I <sub>CBO</sub>	Collector-base current	V <sub>CB</sub> = 20V, I <sub>E</sub> = 0			0.1	uA
I <sub>CEO</sub>	Collector-emitter current	V <sub>CE</sub> = 10V, I <sub>B</sub> = 0			100	uA
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 2mA, V <sub>CE</sub> = 10V	160		460	
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> =100mA, I <sub>B</sub> = 10mA		0.1	0.3	V

#### **♦** hFE Classifications

ZQ	ZR	ZS	
160-260	210-340	290-460	

## PACKAGE OUTLINE Dimensions in mm (1mm = 0.0394)





SYMBOL	MIN.	TYP	MAX.
Α	0.90	1.03	1.13
A1	0.00	0.05	0.10
A2	0.90	1.00	1.10
b	0.30	0.40	0.50
С	0.08	0.11	0.15
D	2.80	2.90	3.00
E	1.20	1.30	1.40
E1	2.35	2.45	2.55
е	0.90	0.95	1.00
e1	1.80	1.90	2.00
L	0.50	0.58	0.65
L1	0.30	0.40	0.50
θ		4°	



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